

BD743 – A – B – C

SILICON POWER TRANSISTORS

The BD743 series are NPN power transistors in a TO-220 envelope.
They are intended for use in power linear and switching application.
High current capability and high power dissipation.
PNP complements are BD744-A-B-C
Compliance to RoHS.

ABSOLUTE MAXIMUM RATINGS

Symbol	Ratings	Value	Unit	
V_{CBO}	Collector-Base Voltage ($I_E=0$)	BD743	50	V
		BD743A	70	
		BD743B	900	
		BD743C	110	
V_{CEO}	Collector-Emitter Voltage ($I_B=0$)	BD743	45	V
		BD743A	60	
		BD743B	80	
		BD743C	100	
V_{EBO}	Emitter-Base Voltage ($I_C=0$)	BD743	5	V
		BD743A		
		BD743B		
		BD743C		
I_C	Collector Current	BD743	15	A
		BD743A		
		BD743B		
		BD743C		
I_{CM}	Collector Peak Current	BD743	20	A
		BD743A		
		BD743B		
		BD743C		
I_B	Base Current	BD743	5	A
		BD743A		
		BD743B		
		BD743C		
P_T	Power Dissipation	$T_C = 25^\circ C$	90	W
		$T_A = 25^\circ C$	2	
T_J	Junction Temperature		150	$^\circ C$
T_s	Storage Temperature range		-65 to +150	

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THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit
R_{thJ-MB}	Junction To Case Thermal Resistance	1.4	°C/W
R_{thJ-A}	Junction To Free Air Thermal Resistance	62.5	°C/W

ELECTRICAL CHARACTERISTICS

$T_C=25^{\circ}C$ unless otherwise noted

Symbol	Ratings	Test Condition(s)	Min	Typ	Max	Unit			
I_{CBO}	Collector Cutoff Current	$V_{BE}=0$ $V_{CB}=50V$	$T_C=25^{\circ}C$	-	-	0.1	BD743		
		$V_{BE}=0$ $V_{CB}=70V$					BD743A		
		$V_{BE}=0$ $V_{CB}=90V$					BD743B		
		$V_{BE}=0$ $V_{CB}=100V$					BD743C		
		$V_{BE}=0$ $V_{CB}=50V$	$T_C=125^{\circ}C$	-	-	5	mA	BD743	
		$V_{BE}=0$ $V_{CB}=70V$						BD743A	
		$V_{BE}=0$ $V_{CB}=90V$						BD743B	
		$V_{BE}=0$ $V_{CB}=100V$						BD743C	
		I_{CEO}	Collector Cutoff Current	$I_B=0$ $V_{CE}=30V$		-	-	0.1	BD743
				$I_B=0$ $V_{CE}=60V$					BD743A
	BD743B								
	BD743C								
I_{EBO}	Emitter Cutoff Current	$V_{EB}=5V, I_C=0$		-	-	0.5	BD743		
							BD743A		
							BD743B		
							BD743C		
V_{CEO}	Collector-Emitter Breakdown Voltage (*)	$I_C=30mA, I_B=0$					BD743		
							BD743A		
							BD743B		
							BD743C		

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ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings			Value			Unit
				Min	Typ	Max	
$V_{CE(SAT)}$	Collector-Emitter saturation Voltage (*)	$I_C = 5\text{ A}, I_B = 500\text{ mA}$	BD743	-	-	1	V
			BD743A				
			BD743B				
			BD743C				
		$I_C = 15\text{ A}, I_B = 5\text{ A}$	BD743	-	-	3	
			BD743A				
			BD743B				
			BD743C				
$V_{BE(on)}$	Base-Emitter Voltage (*)	$I_C = 5\text{ A}, V_{CE} = 4\text{ V}$	BD743	-	-	1	V
			BD743A				
			BD743B				
			BD743C				
		$I_C = 15\text{ A}, V_{CE} = 4\text{ V}$	BD743	-	-	3	
			BD743A				
			BD743B				
			BD743C				
h_{FE}	DC Current Gain (*)	$I_C = 1\text{ A}, V_{CE} = 4\text{ V}$	BD743	40	-	-	-
			BD743A				
			BD743B				
			BD743C				
		$I_C = 5\text{ A}, V_{CE} = 4\text{ V}$	BD743	20	-	150	
			BD743A				
			BD743B				
			BD743C				
		$I_C = 15\text{ A}, V_{CE} = 4\text{ V}$	BD743	5	-	-	
			BD743A				
			BD743B				
			BD743C				

SWITCHING TIMES

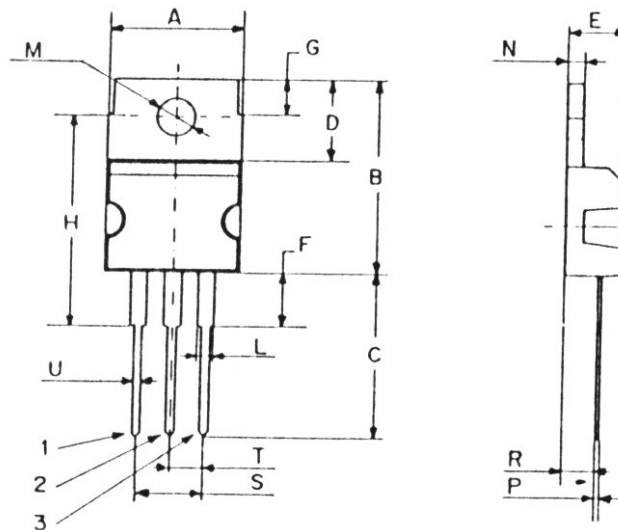
Symbol	Ratings	Test Condition(s)	Value			Unit
			Min	Typ	Max	
t_d	Delay time	$I_C = 5\text{ A}, V_{be} = -4.2\text{ V}$ $I_{B(on)} = -I_{B(off)} = 0.5\text{ A}$ $R_L = 6\ \Omega, t_p = 20\ \mu\text{s}$	-	20	-	ns
t_r	Rise time		-	350	-	
t_s	Storage time		-	500	-	
t_f	Fall time		-	400	-	

(*) Pulse Width $\approx 300\ \mu\text{s}$, Duty Cycle $\angle 2.0\%$

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MECHANICAL DATA CASE TO-220

DIMENSIONS (mm)		
	Min.	Max.
A	9,90	10,30
B	15,65	15,90
C	13,20	13,40
D	6,45	6,65
E	4,30	4,50
F	2,70	3,15
G	2,60	3,00
H	15,75	17,15
L	1,15	1,40
M	3,50	3,70
N	-	1,37
P	0,46	0,55
R	2,50	2,70
S	4,98	5,08
T	2,49	2,54
U	0,70	0,90



Pin 1 :	Base
Pin 2 :	Collector
Pin 3 :	Emitter
Package	Collector

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